

# **Excellent Integrated System Limited**

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

<u>Vishay Semiconductor/Diodes Division</u> <u>FESE16DT-E3/45</u>

For any questions, you can email us directly: <a href="mailto:sales@integrated-circuit.com">sales@integrated-circuit.com</a>

### Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of FESE16DT-E3/45 - DIODE GEN PURP 200V 16A TO220AC

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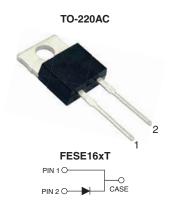


www.vishay.com

### FESE16xT

### Vishay General Semiconductor

### **Ultrafast Plastic Rectifier**



PRIMARY CHARACTERISTICS								
I <sub>F(AV)</sub>	16 A							
V <sub>RRM</sub>	50 V to 600 V							
I <sub>FSM</sub>	250 A							
t <sub>rr</sub>	35 ns, 50 ns							
V <sub>F</sub>	0.975 V, 1.30 V, 1.50 V							
T <sub>J</sub> max.	150 °C							
Package	TO-220AC							
Diode variations	Single die							

#### **FEATURES**

- Power pack
- · Glass passivated pellet chip junction
- · Ultrafast recovery time
- · Low switching losses, high efficiency
- · High forward surge capability
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### **TYPICAL APPLICATIONS**

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, DC/DC converters, and other power switching application.

#### **MECHANICAL DATA**

Case: TO-220AC

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs max.

MAXIMUM RATINGS (T <sub>C</sub> = 25 °C unless otherwise noted)											
PARAMETER	SYMBOL	FESE 16AT	FESE 16BT	FESE 16CT	FESE 16DT	FESE 16FT	FESE 16GT	FESE 16HT	FESE 16JT	UNIT	
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	150	200	300	400	500	600	V	
Maximum RMS voltage	V <sub>RMS</sub>	35	70	105	140	210	280	350	420	V	
Maximum DC blocking voltage	$V_{DC}$	50	100	150	200	300	400	500	600	V	
Maximum average forward rectified current at $T_C = 100  ^{\circ}\text{C}$	I <sub>F(AV)</sub>	16						Α			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	250						Α			
Operating storage and temperature range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150							°C		



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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)												
PARAMETER	TEST CONDITIONS	SYMBOLL		FESE 16FT	FESE 16GT	FESE 16HT	FESE 16JT	UNIT				
Maximum instantaneous forward voltage	16 A	V <sub>F</sub> <sup>(1)</sup>	0.975		1.30		1.50		٧			
Maximum DC reverse current at T <sub>C</sub> = 25 °C		I_	10								μA	
rated DC blocking voltage	T <sub>C</sub> = 100 °C	I <sub>R</sub>	500								μΑ	
Maximum reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1.0 \text{ A},$ $I_{rr} = 0.25 \text{ A}$	t <sub>rr</sub>	35 50				ns					
Typical junction capacitance	4.0 V, 1 MHz	CJ	175			14	15	pF				

#### Note

 $<sup>^{(1)}\,</sup>$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)										
PARAMETER	SYMBOL	YMBOL FESE FESE FESE FESE FESE FESE FESE FES						UNIT		
Typical thermal resistance, junction to case	$R_{ heta JC}$	1.2 °C.				°C/W				

ORDERING INFORMATION (Example)										
PACKAGE	KAGE PREFERRED P/N UNIT WEIGHT (g) PACKAGE CODE BASE QUANTITY DELIVERY MODE									
TO-220AC	FESE16JT-E3/45	1.78	45	50/tube	Tube					

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#### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

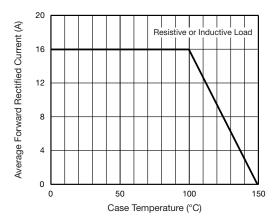


Fig. 1 - Maximum Forward Current Derating Curve

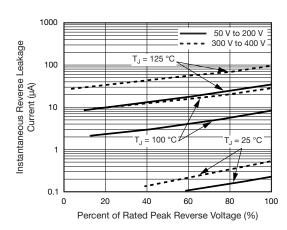


Fig. 4 - Typical Reverse Leakage Characteristics

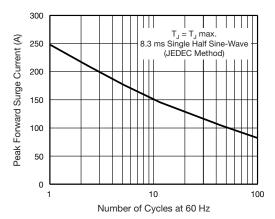


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

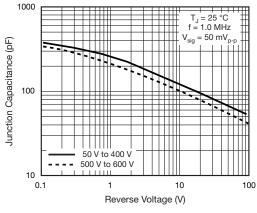


Fig. 5 - Typical Junction Capacitance

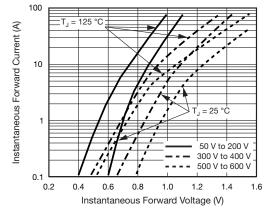


Fig. 3 - Typical Instantaneous Forward Characteristics



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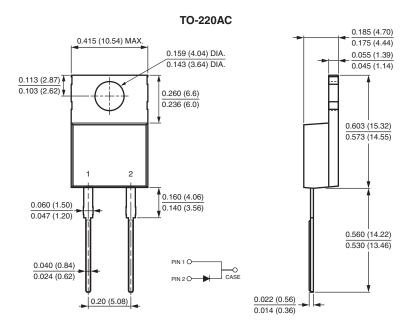
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#### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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